## NSN 5961-00-482-8491

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View Online at https://aerobasegroup.com/nsn/5961-00-482-8491

#### Inclosure Material:

Metal

#### **Overall Length:**

Between 0.320 inches and 0.468 inches

## Mounting Facility Quantity:

1

#### Internal Configuration:

Junction contact

#### Internal Junction Configuration:

Npn

#### **Mounting Method:**

Threaded stud

Features Provided:

Hermetically sealed case

#### **Overall Width Across Flats:**

Between 0.424 inches and 0.437 inches

#### Thread Size:

0.190 inches

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

120.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 8.0 breakdown voltage,

emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

Between 1.00 amperes source cutoff current and 7.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

33.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Precious Material And Location:**

Terminal surfaces gold

#### **Precious Material:**

Gold

#### Test Data Document:

00752-361590 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### **Thread Series Designator:**

Unf

## Terminal Type And Quantity:

3 tab, solder lug

## Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

